

DPG20C400PC

HiPerFRED

 $V_{RRM} = 400 V$

 $I_{FAV} = 2x \quad 10 A$

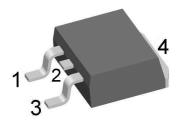
 $t_{rr} = 45 \, \text{ns}$

High Performance Fast Recovery Diode Low Loss and Soft Recovery Common Cathode

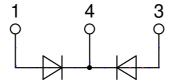
Part number

DPG20C400PC

Marking on Product: DPG20C400PC



Backside: cathode



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviourVery low Irm-values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low Irm reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: TO-263 (D2Pak)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.





Fast Diode					Ratings		
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse blocki	ng voltage	$T_{VJ} = 25^{\circ}C$			400	V
V_{RRM}	max. repetitive reverse blocking vo	oltage	$T_{VJ} = 25^{\circ}C$			400	V
IR	reverse current, drain current	$V_R = 400 \text{ V}$	$T_{VJ} = 25^{\circ}C$			1	μΑ
		$V_R = 400 \text{ V}$	$T_{VJ} = 150$ °C			0.15	mΑ
V _F	forward voltage drop	I _F = 10 A	$T_{VJ} = 25^{\circ}C$			1.32	V
		$I_F = 20 A$				1.51	٧
		I _F = 10 A	T _{VJ} = 150°C			1.03	٧
		$I_F = 20 A$				1.24	٧
I _{FAV}	average forward current	T _C = 150°C	T _{vJ} = 175°C			10	Α
		rectangular d = 0.5					-
V _{F0}	threshold voltage		$T_{VJ} = 175$ °C			0.77	٧
r _F	slope resistance	ss calculation only				19.8	mΩ
R _{thJC}	thermal resistance junction to case	;				2.3	K/W
R _{thCH}	thermal resistance case to heatsin	k			0.25		K/W
P _{tot}	total power dissipation		$T_{C} = 25^{\circ}C$			65	W
I _{FSM}	max. forward surge current	$t = 10 \text{ ms}$; (50 Hz), sine; $V_R = 0 \text{ V}$	$T_{VJ} = 45^{\circ}C$			150	Α
CJ	junction capacitance	$V_R = 200 V$ f = 1 MHz	$T_{VJ} = 25^{\circ}C$		12		pF
I _{RM}	max. reverse recovery current		$T_{VJ} = 25 ^{\circ}\text{C}$		4		Α
	,	$I_F = 10 \text{ A}; V_R = 270 \text{ V}$	$T_{VJ} = 125$ °C		6		Α
t _{rr}	reverse recovery time	$I_F = 10 \text{ A}; V_R = 270 \text{ V}$ -di _F /dt = 200 A/ μ s	$T_{VJ} = 25 ^{\circ}\text{C}$		45		ns
		1	$T_{VJ} = 125$ °C		65		ns





Package	Package TO-263 (D2Pak)			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
I _{RMS}	RMS current	per terminal			35	Α	
T _{vJ}	virtual junction temperature		-59	5	175	°C	
T _{op}	operation temperature		-55	5	150	°C	
T _{stg}	storage temperature		-59	5	150	°C	
Weight				1.5		g	
F _c	mounting force with clip		20)	60	N	

Product Marking XXXXXXXXX Part Number IXYS yywwZ Logo Date Code Location **→**123456 Lot#

Part description

D = Diode

P = HiPerFRED

G = extreme fast

20 = Current Rating [A]

C = Common Cathode

400 = Reverse Voltage [V] PC = TO-263AB (D2Pak) (2)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DPG20C400PC-TRL	DPG20C400PC	Tape & Reel	800	507327
Alternative	DPG20C400PC-TUB	DPG20C400PC	Tube	50	525092

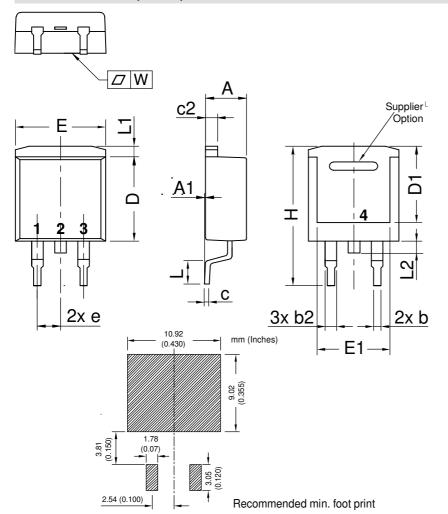
Similar Part	Package	Voltage class
DPG20C400PB	TO-220AB (3)	400
DPG20C400PN	TO-220ABFP (3)	400

Equivalent Circuits for Simulation			* on die level	$T_{VJ} = 175^{\circ}C$
$I \rightarrow V_0$)[R ₀]-	Fast Diode		
V _{0 max}	threshold voltage	0.77		V
$R_{0 \text{ max}}$	slope resistance *	16.6		$m\Omega$





Outlines TO-263 (D2Pak)



Dim.	Millir	neter	Inc	hes	
DIIII.	min	max	min	max	
Α	4.06	4.83	0.160	0.190	
A1	typ.	0.10	typ. 0	0.004	
A2	2.	41	0.095		
b	0.51	0.99	0.020	0.039	
b2	1.14	1.40	0.045	0.055	
С	0.40	0.74	0.016	0.029	
c2	1.14	1.40	0.045	0.055	
D	8.38	9.40	0.330	0.370	
D1	8.00	8.89	0.315	0.350	
D2	2.5		0.098		
Е	9.65	10.41	0.380	0.410	
E1	6.22	8.50	0.245	0.335	
е	2,54	BSC	0,100 BSC		
e1	4.5	28	0.1	69	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	1.02	1.68	0.040	0.066	
W	typ. 0.02	0.040	typ. 0.0008	0.002	

All dimensions conform with and/or within JEDEC standard.

